NSN 5961-01-024-3673

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View Online at https://aerobasegroup.com/nsn/5961-01-024-3673 **Inclosure Material:** Ceramic **Overall Length:** 0.785 inches **Terminal Length:** 0.100 inches **Overall Height:** 0.300 inches **Overall Width:** 0.325 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-116 **Response Time:** 30.0 nanoseconds all transistor **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 collector to emitter voltage/static/base open all transistor and 60.0 collector to base voltage/static/emitter open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 1.9 watts small-signal input power, common-collector absolute all transistor **Capacitance Rating In Picofarads:** 30.0 all transistor **Transfer Ratio:** 35.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:**

N/a

Unit Of Measure:

14 pin Shelf Life:

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Demilitarization:

No

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